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Docket
4/26/02

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

Tatsuya KUNIKIYO : GAU: 2814

SERIAL NO: 09/612,298 :

FILED: JULY 7, 2000 : EXAMINER: CAO, PHAT X.

FOR: SEMICONDUCTOR DEVICE

AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

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TC 2800 MAIL ROOM

SIR:

Responsive to the Office Action dated January 3, 2002, please amend the above-identified application as follows:

IN THE TITLE

Page 1, line 2, delete in its entirety and substitute therefor:

SEMICONDUCTOR DEVICE HAVING MULTILAYER

INTERCONNECTION STRUCTURE

IN THE CLAIMS

Please cancel Claims 2-6 and 16-20 without prejudice.

Please amend the claims as indicated in the marked-up copy to read as follows:

10. (Amended) A semiconductor device comprising:

A / a semiconductor substrate having a main surface along which a semiconductor element is formed;